

September 2008

# **D44C8**

# **NPN Power Amplifier**

· Sourced from process 4P.



1. Base 2. Collector 3. Emitter

## Absolute Maximum Ratings T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	eter Value	
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V
I <sub>C</sub>	Collector Current - Continuous	4.0	Α
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

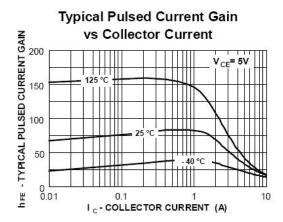
# $\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \text{=} 25 ^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

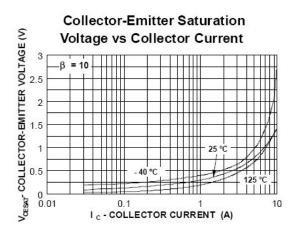
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characteri	stics	•	•	•		•
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0	60			V
I <sub>CES</sub>	Collector-Emitter-(Base)Short	V <sub>CE</sub> = 70V, I <sub>E</sub> = 0			10	μА
I <sub>EBO</sub>	Emitter-Cutoff Current	V <sub>EB</sub> = 5.0V, I <sub>B</sub> = 0			100	μА
On Characteris	stics *					
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = 1V, I <sub>C</sub> = 0.2A V <sub>CE</sub> = 1V, I <sub>C</sub> = 2.0A	40 20		120	
V <sub>CE (sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1.0A,I <sub>B</sub> = 50mA			0.5	V
V <sub>BE (sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1.0A,I <sub>B</sub> = 100mA			1.3	V
Small Signal C	haracteristics					
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V,f = 1.0MHz			100	pF
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> = 20mA, V <sub>CE</sub> = 4.0V			40	pF
t <sub>ON</sub>	$t_{\text{d}}$ , Delay Time $t_{\text{r}}$ , Rise Time	I <sub>C</sub> = 1.0A, I <sub>B1</sub> = I <sub>B2</sub> = 0.1A,		54 490		ns
t <sub>OFF</sub>	$t_{s}$ , Storage Time $t_{f}$ , Fall Time	$V_{CC} = 30V$ , tp = 25 $\mu$ s		636 59		ns

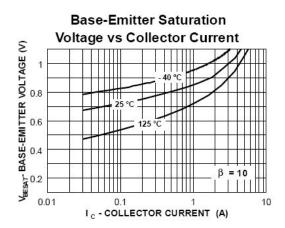
# Thermal Characteristics $T_a$ =25°C unless otherwise noted

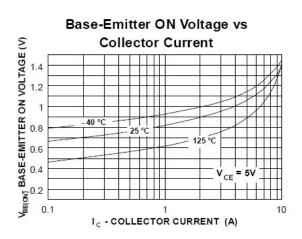
Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	60 480	W mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	2.1	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62.5	°C/W

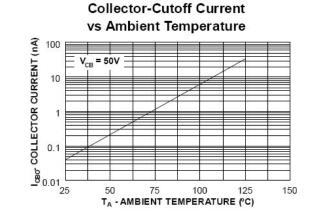
## **Typical Performance Characteristics**















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